

General-Purpose 4ch Electronic Volume with Built-in Advanced Switch

BD3465FV

General Description

BD3465FV is a 4ch electronic volume which has the best audio efficiency in the industry. It has an external sound mixing function (with volume) in the favorite channel for mixing of portable audio and car navigation's guide sound. Also, BD3465FV has a volume switching shock sound prevention technique called "Advanced Switch," supporting the construction of high quality car audio space by simple control.

Features

- Reduce switching noise of volume by using Advanced Switch circuit.
- Mixing for external sound monaural 3ch. It is possible that is mixed to front/Rear output Lch/Rch independently.
- Built-in 3ch ATT for external sound mixing that can be controlled independently.
- Energy saving design resulting in low-current consumption by utilizing the Bi-CMOS process. It has the advantage in quality over scaling down the power heat control of the internal regulators.
- Arranges all I/O terminals together for easier PCB layout and smaller PCB area.
- I²C BUS can be controlled by 3.3V / 5V.

Applications

It is optimal for car audio. It can also be used for car navigation, audio equipment of mini Compo, micro Compo, DVD, TV, etc.

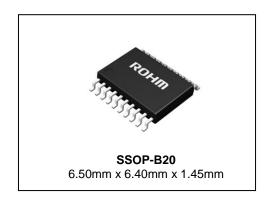
Typical Application Circuit

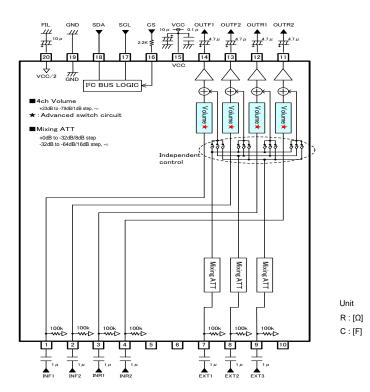
Power Supply Voltage Range: 7.0V to 9.5V Circuit Current (no signal): 25mA(Typ) Total Harmonic Distortion: 0.0004%(Typ) 2.35Vrms(Typ) Maximum Input Voltage: Cross-talk Between Selectors: -105dB(Typ) Volume Control Range: +23dB to -79dB Output Noise Voltage: 1.9µVrms(Typ) Residual Output Noise Voltage: 1.6µVrms(Typ) Operating Temperature Range: -40°C to +85°C

Key Specifications

Package

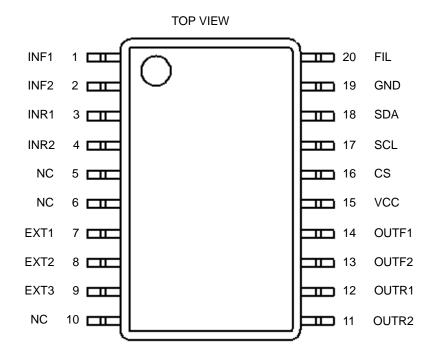
W(Typ) x D(Typ) x H(Max)





OProduct structure: Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

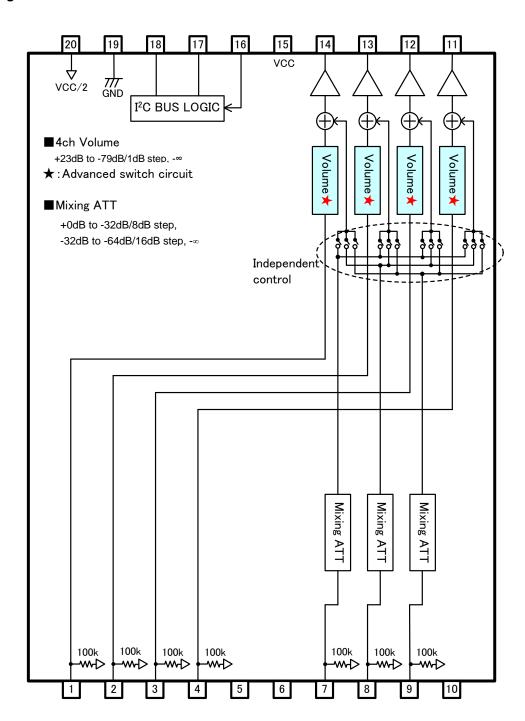
Pin Configuration



Pin Descriptions

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
1	INF1	1ch Front input terminal	11	OUTR2	2ch Rear output terminal
2	INF2	2ch Front input terminal	12	OUTR1	1ch Rear output terminal
3	INR1	1ch Rear input terminal	13	OUTF2	2ch Front output terminal
4	INR2	2ch Rear input terminal	14	OUTF1	1ch Front output terminal
5	NC		15	VCC	Power supply terminal
6	NC		16	CS	Chip select terminal
7	EXT1	1ch External input terminal	17	SCL	I ² C Communication clock terminal
8	EXT2	2ch External input terminal	18	SDA	I ² C Communication data terminal
9	EXT3	3ch External input terminal	19	GND	GND terminal
10	NC		20	FIL	VCC/2 terminal

Block Diagram



Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	Vcc	10.0V	V
Input Voltage	Vin	Vcc+0.3 to GND-0.3	V
Power Dissipation	Pd	0.81 (Note 1)	W
Storage Temperature	Tstg	-55 to +150	°C

(Note 1) This value decreases 6.5mW/°C for Ta=25°C or more when mounted on ROHM standard board. Thermal resistance θja=153.8 (°C/W) Size: 70 x 70 x 1.6(mm3)

Material: FR4 grass epoxy board(3% or less of copper foil area)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions

Parameter	Symbol		Unit		
Faianielei	Symbol	Min	Тур	Max	Offic
Power Supply Voltage	Vcc	7.0	-	9.5	V
Temperature	Topr	-40	-	+85	°C

Electrical Characteristics

(Unless specified, Ta=25°C, V_{CC}=8.5V, f=1kHz, V_{IN}=1Vrms, Rg=600Ω, R_L=10kΩ, INF1 input, Volume 0dB)

Š	<u> </u>		, ,	Limit	·		0 100
ВГОСК	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Circuit Current (No Signal)	ΙQ	-	25	40	mA	No signal
	Voltage Gain	Gv	-1.5	0	+1.5	dB	G _V =20log(V _{OUT} /V _{IN})
	Channel Balance	СВ	-1.5	0	+1.5	dB	CB=G _{V1} -G _{V2}
	Total Harmonic Distortion	THD	-	0.0004	0.05	%	V _{OUT} =1Vrms BW=400Hz-30KHz
RAL	Output Noise Voltage *	V _{NO}	-	1.9	10	μVrms	Rg=0Ω BW=IHF-A
GENERAL	Residual Output Noise Voltage *	V _{NOR}	-	1.6	10	μVrms	Volume=-∞dB Rg=0Ω BW=IHF-A
	Cross-talk Between Channels *	СТС	-	-105	-90	dB	Rg=0Ω CTC=20log(V _{OUT} /V _{IN}) BW=IHF-A
	Ripple Rejection	RR	-	-80	-40	THD	f=100Hz V _{RR} =100mVrms RR=20log(V _{OUT} /V _{CC} IN)

Electrical Characteristics - continued (Unless specified, Ta=25°C, V_{CC}=8.5V, f=1kHz, V_{IN}=1Vrms, Rg=600Ω, R_L=10kΩ, INF1 input, Volume 0dB)

	specified, Ia=25°C, Vcc=8.5V, f=1k	ITZ, VIN-I VI	ilis, Ky–	00012, KL	- TUK\$2, I	nr i inpu	i, volume oub)
BLOCK	Parameter	Symbol		Limit		Unit	Conditions
BLC	Faiaillelei	Symbol	Min	Тур	Max	Offic	Conditions
	Input Impedance	R _{IN_V}	70	100	130	kΩ	
	Maximum Input Voltage	VIM	2	2.35	-	Vrms	V _{IM} at THD+N(V _{OUT})=1% BW=400Hz-30KHz
	Maximum Gain	Gv_bst	21	23	25	dB	Gain=23dB V _{IN} =100mVrms G _V =20log(V _{OUT} /V _{IN})
VOLUME	Maximum Attenuation *	Gv_min	ı	-109	-90	dB	Volume=-∞dB G∨=20log(Vout/Vin) BW=IHF-A
Ģ	Step Resolution	G _{V_STEP}	-	1	-	dB	GAIN&ATT=+23dB to -79dB
>	Gain Set Error	G _{V_ERR}	-2	0	+2	dB	Gain=+1dB to +23dB
	Attenuation Set Error 1	Gv_err1	-2	0	+2	dB	ATT=-1dB to -15dB
	Attenuation Set Error 2	Gv_err2	-3	0	+3	dB	ATT=-16dB to -47dB
	Attenuation Set Error 3	Gv_err3	-4	0	+4	dB	ATT=-48dB to -79dB
	Output Impedance	Rout	-	-	50	Ω	V _{IN} =100mVrms
	Maximum Output Voltage	Vом	2	2.35	-	Vrms	THD+N=1% BW=400Hz-30kHz
⊢	Input Impedance	R _{IN_M}	70	100	130	kΩ	
MIXING ATT	Maximum Attenuation *	G _{M_MIN}	-	-90	-	dB	G _M =20log(V _{OUT} /V _{IN}) BW=IHF-A, ATT=-∞dB
	Step Resolution 1	GM_STEP1	-	8	-	dB	ATT=0dB to -32dB
Σ	Step Resolution 2	GM_STEP2	-	16	-	dB	ATT=-32dB to -64dB

VP-9690A(Average value detection, effective value display) filter by Matsushita Communication is used for * measurement. Phase between input / output is same.

Typical Performance Curves

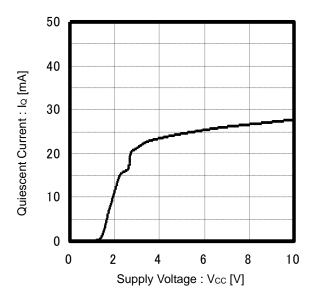


Figure 1. Quiescent Current vs Supply Voltage

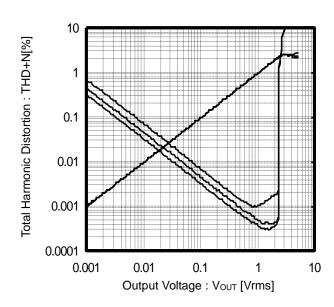


Figure 2. Total Harmonic Distortion vs Output Voltage

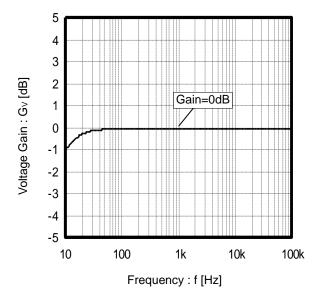


Figure 3. Voltage Gain vs Frequency

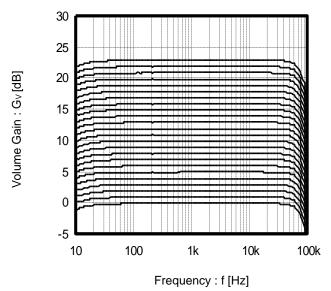


Figure 4. Volume Gain vs Frequency (0dB to +23dB)

Typical Performance Curves - continued

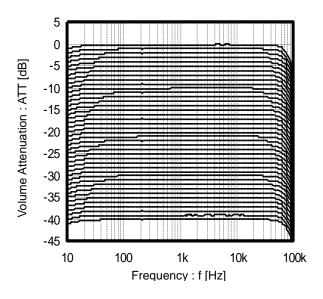


Figure 5. Volume Gain vs Frequency 1 (0dB to -40dB)

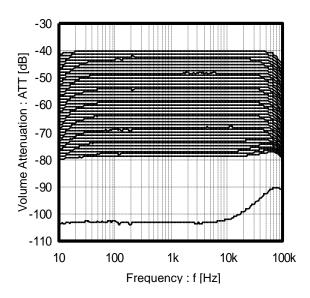


Figure 6. Volume Gain vs Frequency 2 (-41dB to -79dB)

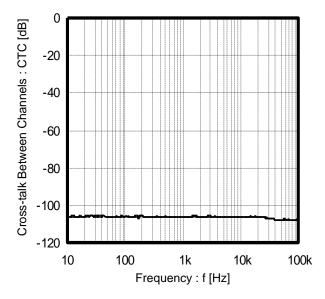


Figure 7. Cross-Talk Between Channels vs Frequency

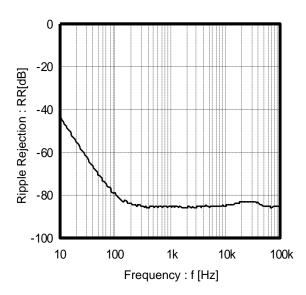


Figure 8. Ripple Rejection Ratio vs Frequency

Typical Performance Curves - continued

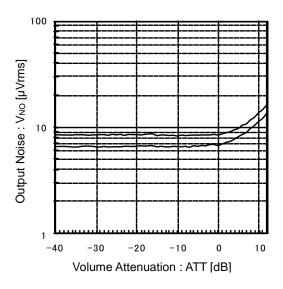


Figure 9. Output Noise vs Volume Attenuation

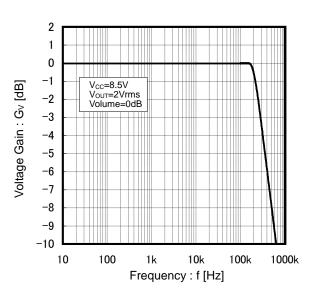


Figure 10. Volume Gain of Large Output Level vs Frequency

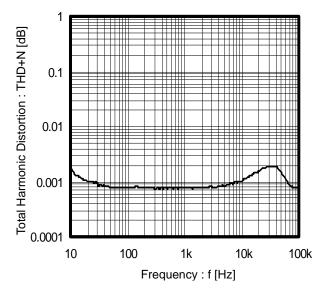


Figure 11. Total Harmonic Distortion vs Frequency

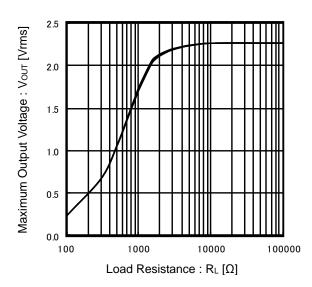
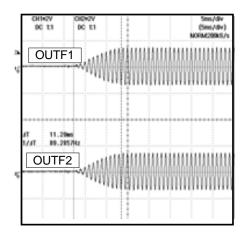


Figure 12. Maximum Output Voltage vs Load Resistance

Typical Performance Curves – continued



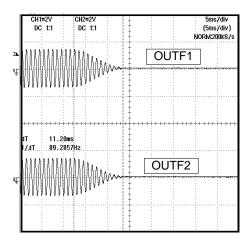


Figure 13. Advanced Switch 1

Figure 14. Advanced Switch 2

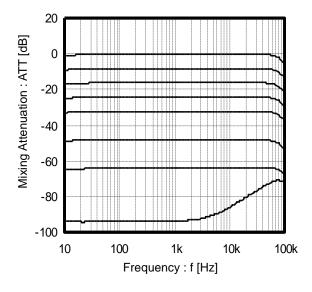


Figure 15. Mixing Attenuation vs Frequency

Timing Chart

Control Signal Specifications

(1) Electrical Specifications and Timing for Bus Lines and I/O Stages

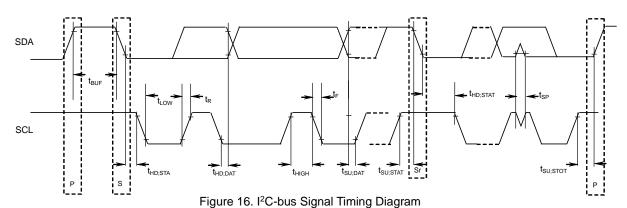


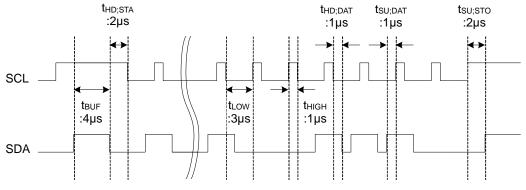
Table 1 Characteristics of the SDA and SCL bus lines for I²C-bus devices (Unless specified, Ta=25°C, Vcc=8.5V)

	Parameter	Cumbal	Fast-mod	e I ² C-bus	Unit
	Parameter	Symbol	Min	Max	Unit
1	SCL clock frequency	fscL	0	400	kHz
2	Bus free time between a STOP and START condition	t BUF	1.3	-	μS
3	Hold time (repeated) START condition. After this period, the first clock	4	0.6		e
3	pulse is generated	t _{HD;STA}	0.6	-	μS
4	LOW period of the SCL clock	tLOW	1.3	-	μS
5	HIGH period of the SCL clock	thigh	0.6	-	μS
6	Set-up time for a repeated START condition	tsu;sta	0.6	-	μS
7	Data hold time	t _{HD;DAT}	0 (Note)	-	μS
8	Data set-up time	tsu;dat	100	-	ns
9	Set-up time for STOP condition	tsu;sto	0.6	-	μS

All values referred to VIH Min and VIL Max Levels (see Table 2). (Note) To avoid sending right after the fall-edge of SCL (VIH min of the SCL signal), the transmitter sets a holding time of 300ns or more for the SDA signal. About 7(t_{HD:DAT}), 8(t_{SU:DAT}), make it the setup which a margin is fully in .

Table 2 Characteristics of the SDA and SCL I/O stages for I²C-bus devices

	Parameter	Symbol	Fast-mod	de devices	Unit
	Falametei	Symbol	Min	Max	Offic
10	LOW level input voltage	V_{IL}	-0.5	+1	V
11	HIGH level input voltage	VIH	2.3	-	V
12	Pulse width of spikes which must be suppressed by the input filter.	tsp	0	50	ns
13	LOW level output voltage (open drain or open collector) at 3mA sink current	V _{OL1}	0	0.4	٧
14	Input current of each I/O pin with an input voltage between 0.4V and 4.5V	I	-10	+10	μA



SCL clock frequency: 250 kHz

Figure 17. I²C Command Data Transmission Timing Diagram

80H 84H

(2) I²C BUS FORMAT

	MSB LSB		MSB	LSB	MSB	LSB						
S	Slave Address	Α	Select Addres	ss A		Data	Α	Р				
1bit	8bit	1bit	8bit	1bit		8bit	1bit	1bit				
	S		Start condition (Recognition of start bit)									
	Slave Address	= Re	= Recognition of slave address. The first 7 bits correspond to the slave address.									
		The least significant bit is "L" which corresponds to write mode.										
	Α	= ACKNOWLEDGE bit (Recognition of acknowledgement)										
	Select Address	= Select address corresponding to volume, bass or treble.										
	Data	= Data on every volume and tone.										
	Р	= Stop condition (Recognition of stop bit)										

(3) I²C BUS Interface Protocol

(a) Basic format

S	Slave Address	Α	Select Address	Α	Data	Α	Р
MS	SB LSB	M	SB LSB	N	ISB LSB		

(b) Automatic increment (Select Address increases (+1) according to the number of data.)

	S	Slave Address	Α	Select Address	Α	Da	ta1	Α	Data2	Α		DataN	Α	Р
_	MS	SB LSB	М	SB LSB	М	SB	LSB	MSI	B LSB		M	ISB LSB		

(Example) ①Data1 shall be set as data of address specified by Select Address.

- ②Data2 shall be set as data of address specified by Select Address +1.
- ③DataN shall be set as data of address specified by Select Address +N-1.

(c) Configuration unavailable for transmission (In this case, only Select Address1 is set.)

_							_		·				-	_	
	\circ	Slave Address		Select Address	-1 I A		Data		Select Addres	c ?	1 / 1	Data	Α	. D .	
	9 1	Diave Addiess	\sim	Select Address	רו וכ		Dala	\sim	Select Addres	3 Z	\sim	Dala	$\overline{}$		
	140		B 4.0		D 144		1.00		00	00	N 4 C	n 100			
	MSE	S LSB	MS	SB LS	B MS	SB	LSB	IVI.	SB L	SB	MS	SB LSB			
						_			-						
		(Nioto)If any	data	is transmitted as	Solo	a+ /	\ ddraac	· 2 n	avt to data it is	rooo	ania	, a d			
		(INOLE)II ally	uala	is transmitted as	5 Sele	\cup l F	100165) – 11	exi io dala, il is	1600	griiz	.eu			
		` ,				_					•				
		as c	atar	not as Select Ac	idress	'									
		ao c	autu,	1101 40 0010017 10											

(4) Slave Address

Because the slave address can be changed by the setting of CS, it is possible to use two chips at the same time on identical BUS.

	MSB							LSB
SEL Voltage Condition	A6	A5	A4	А3	A2	A1	A0	R/W
GND to 0.2 x Vcc	1	0	0	0	0	0	0	0
0.8 x Vcc to Vcc	1	0	0	0	0	1	0	0

Establish the CS voltage to define the setting.

(5) Select Address & Data

	Select	MSB			Da	ata			LSB
Items to be set	Address (hex)	D7	D6	D5	D4	D3	D2	D1	D0
Initial Setup 1	01	0	0	0	0	0	1	0	0
Volume 1ch Front	28			Vo	olume Gain	/ Attenuati	on		
Volume 2ch Front	29			Vo	olume Gain	/ Attenuati	on		
Volume 1ch Rear	2A			Vo	olume Gain	/ Attenuati	on		
Volume 2ch Rear	2B			Vo	olume Gain	/ Attenuati	on		
Test Mode1	2C	1	1	1	1	1	1	1	1
Test Mode2	2D	1	1	1	1	1	1	1	1
EXT 1 ON/OFF	30	EXT1	EXT1	EXT1	EXT1	EXT1	EXT1	0	0
EXT TON/OFF	30	S2	S1	R2	R1	F2	F1	U	U
EXT 2 ON/OFF	31	EXT2	EXT2	EXT2	EXT2	EXT2	EXT2	0	0
EXT 2 ON/OFF	31	S2	S1	R2	R1	F2	F1	U	U
EXT 3 ON/OFF	32	EXT3	EXT3	EXT3	EXT3	EXT3	EXT3	0	0
EXT 3 ON/OFF	32	S2	S1	R2	R1	F2	F1	U	U
EXT 1 ATT	33	0	0	0	0	0	EX	T1 Attenua	tion
EXT 2 ATT	34	0	0	0	0	0	EXT2 Attenuation		
EXT 3 ATT	35	0	0	0	0	0	EXT3 Attenuation		
Test Mode3	F0	0	0	0	0	0	0	0	0
System Reset	FE	1	0	0	0	0	0	0	1

Advanced Switch

(Note)

- 1. The Advanced Switch works in the latch part while changing from one function to another.
- 2. Upon continuous data transfer, the Select Address rolls over because of the automatic increment function, as shown below.

$$\rightarrow$$
01 \rightarrow 28 \rightarrow 29 \rightarrow 2A \rightarrow 2B \rightarrow 2C \rightarrow 2D \rightarrow 30 \rightarrow 31 \rightarrow 32 \rightarrow 33 \rightarrow 34 \rightarrow 35 $-$

3. When changing "EXT = ON/OFF" and "EXT Attenuation", does not correspond for advance switch. Therefore, please do the measure that applies mute on the side of a set.

Select address 28, 29, 2A, 2B(hex)

Coin 9 ATT	MSB		Volum	e Gair	n/Atten	uation	1	LSB
Gain & ATT	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
(NI=4=)	0	0	0	0	0	0	0	1
Prohibition (Note)	÷	• •	:	• •	••	:	:	:
	0	1	1	0	1	0	0	0
23dB	0	1	1	0	1	0	0	1
22dB	0	1	1	0	1	0	1	0
21dB	0	1	1	0	1	0	1	1
:	:	:	:	:	:	:	:	:
-78dB	1	1	0	0	1	1	1	0
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition (Note)	:	:	:	:	:	:	:	:
	1	1	1	1	1	1	1	0
-∞dB	1	1	1	1	1	1	1	1

(Note) Gain is set to "-∞dB" when sending "Prohibition data".

Select address 30, 31, 32(hex)

MODE	MSB	MSB EXT1 F1							
MODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	EXT1	EXT1	EXT1	EXT1	0	0	0	
ON	S2	S1	R2	R1	F2	1	Ü	0	

MODE	MSB	MSB EXT1 F2							
MODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	EXT1	EXT1	EXT1	0	EXT1	0	0	
ON	S2	S1	R2	R1	1	F1	U	U	

MODE	MSB		EXT1 R1								
MODE	D7	D6	D5	D4	D3	D2	D1	D0			
OFF	EXT1	EXT1	EXT1	0	EXT1	EXT1	0	0			
ON	S2	S1	R2	1	F2	F1	U	U			

MODE	MSB		EXT1 R2							
WIODE	D7	D6	D5	D4	D3	D2	D1	D0		
OFF	EXT1	EXT1	0	EXT1	EXT1	EXT1	0	0		
ON	S2	S1	1	R1	F2	F1	U	U		

MODE	MSB	EXT1 S1							
IVIODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	0	EXT1	EXT1	EXT1	EXT1	0	0	
ON	S2	1	R2	R1	F2	F1	U	U	

MODE	MSB		LSB					
WIODE	D7	D6	D5	D4	D3	D2	D1	D0
OFF	0	EXT1	EXT1	EXT1	EXT1	EXT1	0	0
ON	1	S1	R2	R1	F2	F1	U	U

:Initial condition

Select address 33, 34, 35(hex)

Gain	MSB		E	XT Atte	enuatio	on .		LSB
Gaiii	D7	D6	D5	D4	D3	D2	D1	D0
0dB						0	0	0
-8dB						0	0	1
-16dB						0	1	0
-24dB	0	0	0	0	0	0	1	1
-32dB		U	U	U	U	1	0	0
-48dB						1	0	1
-64dB						1	1	0
-∞dB						1	1	1

:Initial condition

(6) About Power ON Reset

Initialization inside IC is carried out at one of supply voltage circuits. Initial data is sent to all addresses at supply voltage ON. Mute is ON until this initial data is sent.

Parameter	Cumbal	Limit		Unit	Conditions	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Rise Time of VCC	trise	20	-	-	µsec	Vcc rise time from 0V to 3V
VCC Voltage of Release Power ON Reset	V _{POR}	-	4.1	-	V	

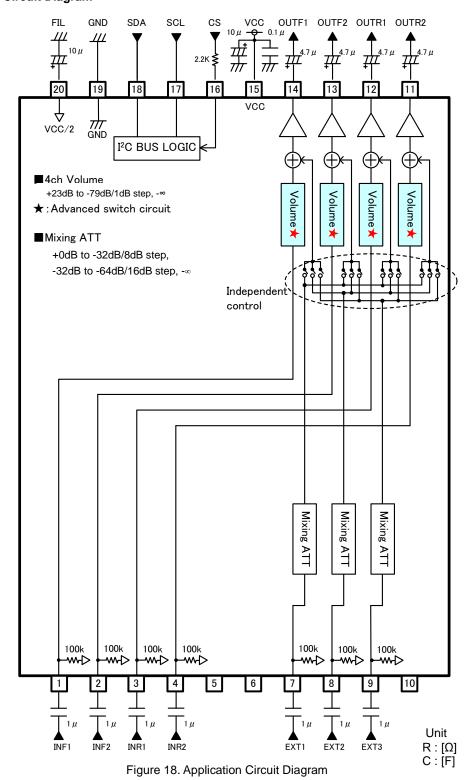
Application Information

1. Volume Gain/Attenuation of the details

	me Ga	ain/At	tenua	ation (of the	deta	ils										
(dB)	D7	D6	D5	D4	D3	D2	D1	D0	(dB)	D7	D6	D5	D4	D3	D2	D1	D0
+23	0	1	1	0	1	0	0	1	-29	1	0	0	1	1	1	0	1
+22	0	1	1	0	1	0	1	0	-30	1	0	0	1	1	1	1	0
+21	0	1	1	0	1	0	1	1	-31	1	0	0	1	1	1	1	1
+20	0	1	1	0	1	1	0	0	-32	1	0	1	0	0	0	0	0
+19	0	1	1	0	1	1	0	1	-33	1	0	1	0	0	0	0	1
+18	0	1	1	0	1	1	1	0	-34	1	0	1	0	0	0	1	0
+17	0	1	1	0	1	1	1	1	-35	1	0	1	0	0	0	1	1
+16	0	1	1	1	0	0	0	0	-36	1	0	1	0	0	1	0	0
+15	0	1	1	1	0	0	0	1	-37	1	0	1	0	0	1	0	1
+14	0	1	1	1	0	0	1	0	-38	1	0	1	0	0	1	1	0
+13	0	1	1	1	0	0	1	1	-39	1	0	1	0	0	1	1	1
+12	0	1	1	1	0	1	0	0	-40	1	0	1	0	1	0	0	0
+11	0	1	1	1	0	1	0	1	-41	1	0	1	0	1	0	0	1
+10	0	1	1	1	0	1	1	0	-42	1	0	1	0	1	0	1	0
+9	0	1	1	1	0	1	1	1	-43	1	0	1	0	1	0	1	1
+8	0	1	1	1	1	0	0	0	-44	1	0	1	0	1	1	0	0
+7	0	1	1	1	1	0	0	1	-45	1	0	1	0	1	1	0	1
+6	0	1	1	1	1	0	1	0	-46	1	0	1	0	1	1	1	0
+5	0	1	1	1	1	0	1	1	-47	1	0	1	0	1	1	1	1
+4	0	1	1	1	1	1	0	0	-48	1	0	1	1	0	0	0	0
+3	0	1	1	1	1	1	0	1	-49	1	0	1	1	0	0	0	1
+2	0	1	1	1	1	1	1	0	-50	1	0	1	1	0	0	1	0
+1	0	1	1	1	1	1	1	1	-51	1	0	1	1	0	0	1	1
0	1	0	0	0	0	0	0	0	-52	1	0	1	1	0	1	0	0
-1	1	0	0	0	0	0	0	1	-53	1	0	1	1	0	1	0	1
-2	1	0	0	0	0	0	1	0	-54	1	0	1	1	0	1	1	0
-3	1	0	0	0	0	0	1	1	-55	1	0	1	1	0	1	1	1
-4	1	0	0	0	0	1	0	0	-56	1	0	1	1	1	0	0	0
-5	1	0	0	0	0	1	0	1	-57	1	0	1	1	1	0	0	1
-6	1	0	0	0	0	1	1	0	-58	1	0	1	1	1	0	1	0
-7	1	0	0	0	0	1	1	1	-59	1	0	1	1	1	0	1	1
-8	1	0	0	0	1	0	0	0	-60	1	0	1	1	1	1	0	0
-9	1	0	0	0	1	0	0	1	-61	1	0	1	1	1	1	0	1
-10	1	0	0	0	1	0	1	0	-62	1	0	1	1	1	1	1	0
-11	1	0	0	0	1	0	1	1	-63	1	0	1	1	1	1	1	1
-12	1	0	0	0	1	1	0	0	-64	1	1	0	0	0	0	0	0
-13	1	0	0	0	1	1	0	1	-65	1	1	0	0	0	0	0	1
-14	1	0	0	0	1	1	1	0	-66	1	1	0	0	0	0	1	0
-15	1	0	0	0	1	1	1	1	-67	1	1	0	0	0	0	1	1
-16	1	0	0	1	0	0	0	0	-68	1	1	0	0	0	1	0	0
-17	1	0	0	1	0	0	0	1	-69	1	1	0	0	0	1	0	1
-17	1	0	0	1	0	0	1	0	-70	1	1	0	0	0	1	1	0
-18 -19	1	0	0	1	0	0	1	1	-70 -71	1	1	0	0	0	1	1	1
					_									_	0	0	
-20 21	1	0	0	1	0	1	0	0	-72	1	1	0	0	1		_	0
-21	1	0			_	1	0	1	-73	1	1	0	0	1	0	0	1
-22	1	0	0	1	0	1	1	0	-74	1	1	0	0	1	0	1	0
-23	1	0	0	1	0	1	1	1	-75	1	1	0	0	1	0	1	1
-24	1	0	0	1	1	0	0	0	-76	1	1	0	0	1	1	0	0
-25	1	0	0	1	1	0	0	1	-77	1	1	0	0	1	1	0	1
~~	_	,	_				1	0	-78	1	1	0	0	1	1	1	0
-26	1	0	0	1	1	0								_			_
-26 -27 -28	_	0 0	0 0	1 1 1	1 1 1	0	1 0	1 0	-79 -∞	1	1	0	0	1	1	1	1

: Initial condition

2. Application Circuit Diagram



Notes on wiring

- ① Please connect the decoupling capacitor of the power supply in the shortest distance as much as possible to GND.
- ② Lines of GND shall be one-point connected.
- ③ Wiring pattern of Digital shall be away from that of analog unit and cross-talk shall not be acceptable.
- Lines of SCL and SDA of I²C BUS shall not be parallel if possible. The lines shall be shielded, if they are adjacent to each other.
- ⑤ Lines of analog input shall not be parallel if possible. The lines shall be shielded, if they are adjacent to each other.

Power Dissipation

About the thermal design by the IC

Characteristics of an IC have a great deal to do with the temperature at which it is used, and exceeding absolute maximum ratings may degrade and destroy elements. Careful consideration must be given to the heat of the IC from the two standpoints of immediate damage and long-term reliability of operation.

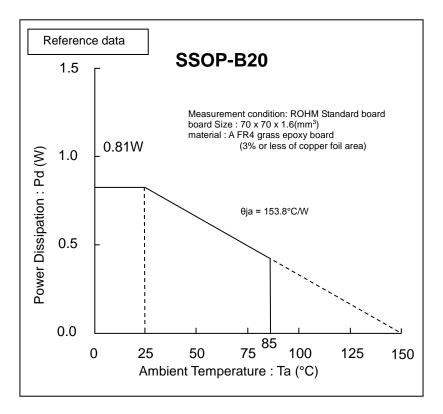


Figure 19. Temperature Derating Curve (SSOP-B20)

(Note) Values are actual measurements and are not guaranteed.

Power dissipation values vary according to the board on which the IC is mounted.

I/O Equivalent Circuits

Terminal Name	Terminal Voltage	Equivalent Circuit	Terminal Description
INF1 INF2 INR1 INR2 EXT1 EXT2 EXT3	4.25	VCC	Signal input terminal. The input impedance is 100kΩ(typ).
OUTR2 OUTR1 OUTF2 OUTF1	4.25	VCC GND	Fader output terminal.
cs	-	VCC GND	Slave address selection terminal. "CS" is "High" to slave address "84 H" "CS" is "Low" to slave address "80 H"

The values in the input/output equivalent circuits are reference values only and are not guaranteed.

I/O Equivalent Circuits - continued

	Equivalent Circuits – continued								
Terminal Name	Terminal Voltage	Equivalent Circuit Terminal Description							
vcc	8.5		Power supply terminal.						
SCL	-	VCC O 1.65V	Clock input terminal of I ² C BUS communication.						
SDA	-	VCC O I.65V	Data input terminal of I ² C BUS communication.						
GND	0		Ground terminal.						
FIL	4.25	VCC	Voltage terminal for reference bias of analog signal system. The simple pre-charge circuit and simple discharge circuit for an external capacitor are built in.						

The values in the input/output equivalent circuits are reference values only and are not guaranteed.

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

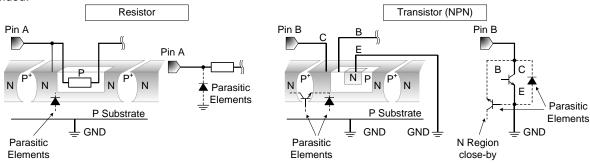
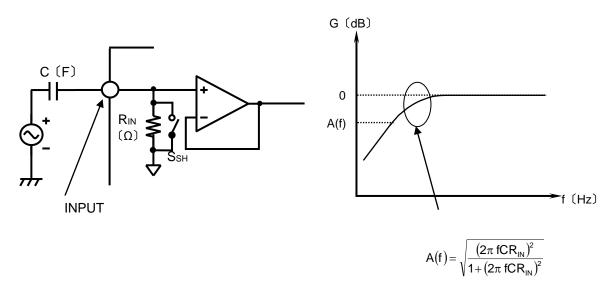


Figure 20. Example of monolithic IC structure

13. About a Signal Input Part

About Input Coupling Capacitor Constant Value

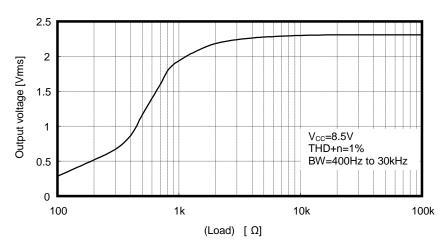
The constant value of input coupling capacitor C(F) is decided with respect to the input impedance $R_{IN}(\Omega)$ at the input signal terminal of the IC. The first HPF characteristic of RC is composed.



14. About Output Load Characteristics

The usages of output load are below (reference). Please use more than $10[k\Omega]$ (TYP) load.

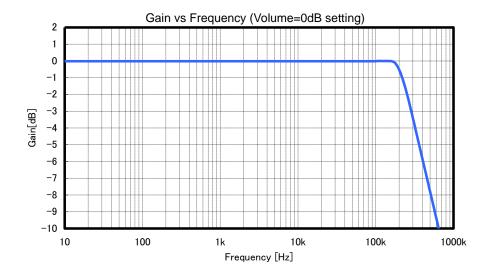
Output pin on target					
Pin Name	Pin Name				
OUTF1	OUTR1				
OUTE2	OLITP2				



Output Load Characteristic at V_{CC}=8.5V. (Reference)

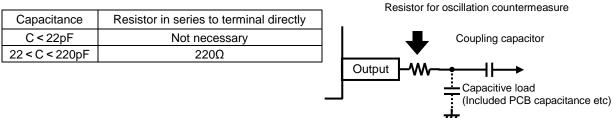
15. Frequency Characteristic at Large Output Level

High slew-rate amplifiers are used for high quality sound. This IC corresponds to "192kHz sampling on DVD-Audio" which is highest quality. Output level is "2Vrms, 192kHz flat(typ)". (See the below graph (reference)).



16. Oscillation Countermeasure for Volume Outputs at Power Supply ON/OFF

If using higher capacitor than 22pF at volume outputs, oscillation may occur for a moment when turning ON/OFF power supply (when Vcc is about 3V to 4 V). As oscillation countermeasure, insert resistor in series to terminal directly as below, and set volume output mute outside this device when turning ON/OFF the power supply.



17. I2C BUS Transferring Data

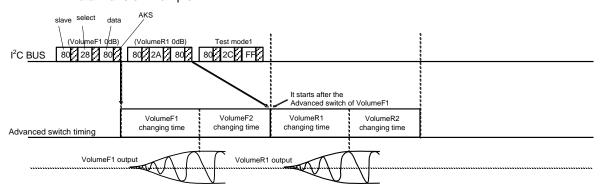
[1] Types of Data Transfer

- 1-1. The data transfer without Advanced Switch (data transfer without data latching format) does not have regulations on transferring data.
- 1-2. The data transfer with Advanced Switch (data transfer with data latching format) does not have regulations on transferring data too. But Advanced Switch data transfer follows the order in [2].

[2] Advanced Switch Data Transfer

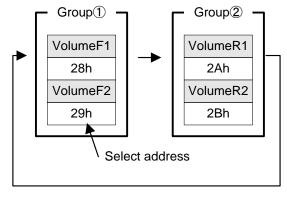
2-1. The timing chart of Advanced Switch data transfer is as follows.

■ Data Transfer Example 1



(Note) It is the same even if it transfers data in auto increment mode.

There are no timing regulations in I²C BUS data transfer. But the changing time starts after the end of the present change. In addition, the timing of Advanced Switch is not dependent on transferring data turn. Instead, it follows the following turn.

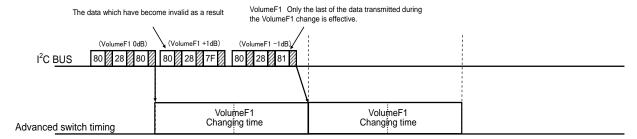


Advanced Switch Start Turn

(Note) The block in the same group can start the Advanced Switch at the same time.

■ Data Transfer Example 2

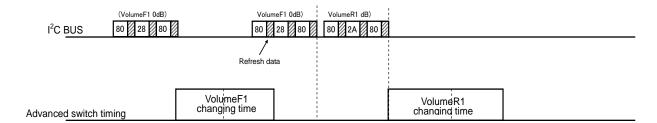
Priority is given to the data of the same select address when it is transferred to the timing which Advanced Switch has not ended. In addition, when two or more data are transferred to the same select address, the end transferred data is effective.



■ Data Transfer Example 3

Refresh data is the same as the present setup data, therefore Advanced Switch does not change.

The gain change data of other channels are transferred after refresh data as shown below.



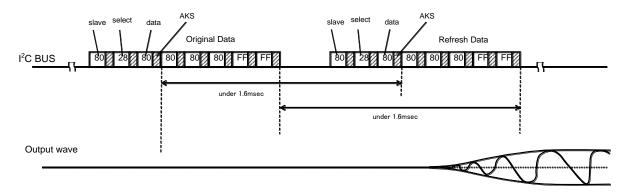
[3] Attention on Transferring Data

BD3465FV cannot set the data transfer from a microcomputer correctly on very rare occasions. In such cases, the following phenomenon may occur.

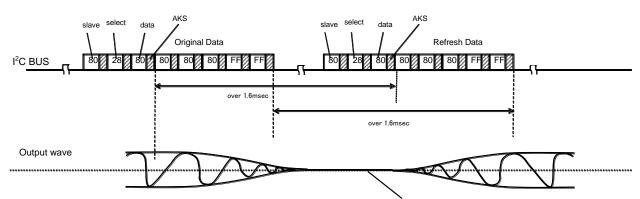
- 1. Volume gain does not change.
- 2. Volume gain changes to MUTE.

Therefore, the data transfer from a microcomputer should send data as shown in the following conditions.

When sending the Volume change data, please send the same data twice as below.

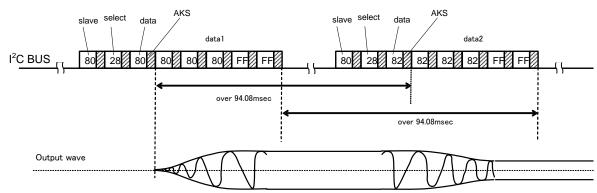


If Refresh data can't be sent like ①timing, the output wave may be put on mute momentarily.

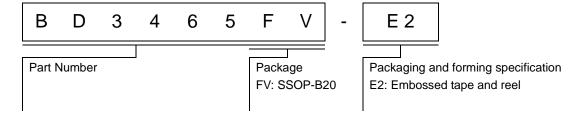


Output wave may not change the gain or may be mute until refresh data reception.

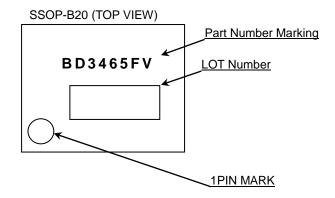
② If Volume change data can send over 94.08msec interval transferring data, there is no need to send Refresh data.

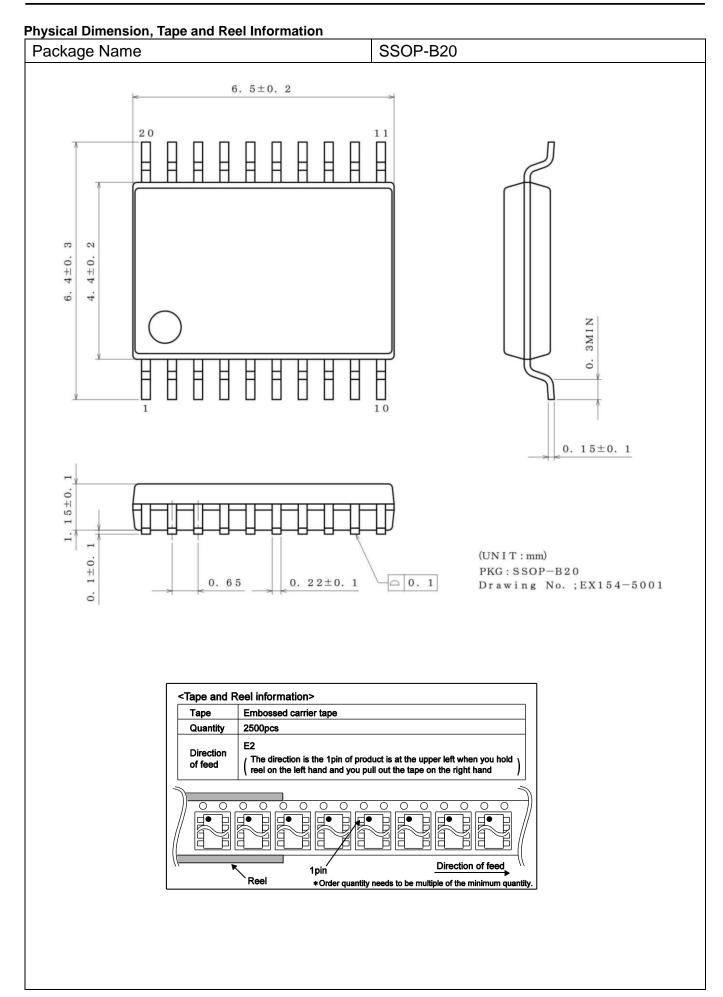


Ordering Information



Marking Diagram





Revision History

Date	Revision	Changes
16.Dec.2015	001	New Release

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CLASSIV	CLASSⅢ	CLASSⅢ	

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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
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